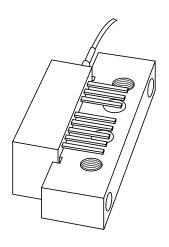
DISCRETE SEMICONDUCTORS

DATA SHEET



BGO847 870 MHz optical receiver

Product specification Supersedes data of 2002 Dec 10 2003 Nov 06





870 MHz optical receiver

BGO847

FEATURES

- · Excellent linearity
- Extremely low noise up to 870 MHz
- Excellent flatness (straight line)
- · Standard CATV outline
- Rugged construction
- · Gold metallization ensures excellent reliability
- High optical input power range.

APPLICATIONS

 CATV optical node systems operating in the 40 to 870 MHz frequency range.

DESCRIPTION

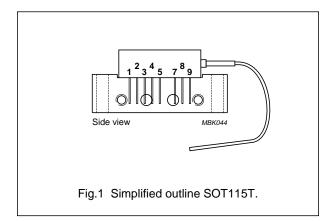
High dynamic range optical receiver amplifier module in a standard SOT115T package where the non-jacketed fibre has no connector.

The amplifier supply voltage pin and the photo diode bias voltage pin both connect to 24 V (DC).

The module has a monomode optical input suitable for 1290 to 1600 nm wavelengths, a terminal to monitor the photo diode current and an electrical output having a characteristic impedance of 75 Ω .

PINNING

PIN	DESCRIPTION	
1	monitor current	
2	common	
3	common	
4	+V _B of the photo diode	
5	+V _B of the amplifier	
7	common	
8	common	
9	output	



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		40	870	MHz
S ₂₂	output return losses	f = 40 to 870 MHz	11	_	dB
	optical input return losses		45	_	dB
d_2	second order distortion	f = 854.5 MHz	_	-63	dB
F	equivalent noise input	f = 40 to 750 MHz	_	7	pA/√Hz
I _{tot}	total current consumption (DC)	V _B = 24 V	175	205	mA

CAUTION

This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling. For further information, refer to Philips specs.: SNW-EQ-608, SNW-FQ-302A and SNW-FQ-302B.

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HANDLING

Fibreglass optical coupling: maximum tensile strength = 5 N; minimum bending radius = 35 mm.

ORDERING INFORMATION

TYPE		PACKAGE	
NUMBER NAME DESCRIPTION		DESCRIPTION	VERSION
BGO847	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; optical input; 9 gold-plated in-line leads	SOT115T

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		40	870	MHz
T _{stg}	storage temperature		-40	+85	°C
T _{mb}	operating mounting base temperature		-20	+85	°C
Pin	optical input power	continuous	_	5	mW
ESD	ESD sensitivity	human body model; R = 1.5 k Ω ; C = 100 pF	500	_	V

CHARACTERISTICS

Bandwidth 40 to 870 MHz; V_B = 24 V; T_{mb} = 30 °C; Z_L = 75 Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
S	responsivity	λ = 1300 nm	800	_	_	V/W
ΔS	responsivity difference	resp at T_{mb} = 85 °C – resp at T_{mb} = 30 °C; f = 870 MHz	-	-50	_	V/W
FL	flatness straight line	peak to valley; f = 40 to 870 MHz	_	_	1	dB
SL	slope straight line	f = 40 to 870 MHz	0	_	2	dB
ΔSL	slope difference	slope at T_{mb} = 85 °C – slope at T_{mb} = 30 °C	_	-0.35	-	dB
S ₂₂	output return losses	f = 40 to 870 MHz	11	_	_	dB
	optical input return losses		40	_	_	dB
d_2	second order distortion	f _m = 54 MHz; notes 1 and 3	_	_	-73	dB
		f _m = 446.5 MHz; notes 1 and 4	_	_	-68	dB
		f _m = 548.5 MHz; notes 1 and 5	_	_	-67	dB
		f _m = 746.5 MHz; notes 1 and 6	_	_	-63	dB
		f _m = 854.5 MHz; notes 1 and 7	_	_	-63	dB
Δd_2	second order distortion difference	d ₂ at T _{mb} = 85 °C - d ₂ at T _{mb} = 30 °C	-	2.5	_	dB
		d_2 at T_{mb} = -20 °C $-d_2$ at T_{mb} = 30 °C	_	-1.5	_	dB

870 MHz optical receiver

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
d ₃	third order distortion	f _m = 55.25 MHz; notes 2 and 8	_	_	-80	dB
		f _m = 445.25 MHz; notes 2 and 9	_	_	-75	dB
		f _m = 547.25 MHz; notes 2 and 10	_	_	-75	dB
		f _m = 745.25 MHz; notes 2 and 11	_	_	-75	dB
		f _m = 853.25 MHz; notes 2 and 12	_	_	-73	dB
Δd_3	third order distortion difference	d_3 at T_{mb} = 85 °C $-d_3$ at T_{mb} = 30 °C	_	1	_	dB
		d_3 at $T_{mb} = -20 \text{ °C} - d_3$ at $T_{mb} = 30 \text{ °C}$	_	-1	_	dB
F	equivalent input noise	f = 40 to 750 MHz	-	-	7	pA/√Hz
		f = 750 to 870 MHz	-	-	8	pA/√Hz
s_{λ}	spectral sensitivity	$\lambda = 1310 \pm 20 \text{ nm}$	0.85	-	_	A/W
		λ = 1550 ±20 nm	0.9	_	_	A/W
λ	optical wavelength		1290	-	1600	nm
L	length of optical fibre	fibre; SM type; 9/125 μm	1	_	_	m
I _{tot}	total current consumption (DC)	$T_{mb} = -20 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$	175	_	205	mA
I _{bias}	diode bias current at pin 4 (DC)		_	_	25	mA

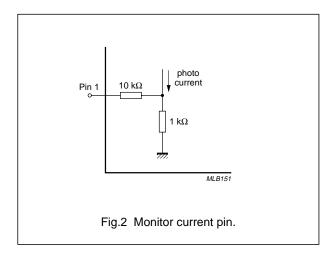
Notes

- 1. Two laser test; each laser with 40% modulation index; Popt = 1 mW (total).
- 2. Three laser test; each laser with 60% modulation index; Popt = 1 mW (total).
- 3. $f_m = 54$ MHz; $f_p = 187.25$ MHz; $f_q = 133.25$ MHz.
- 4. $f_m = 446.5 \text{ MHz}$; $f_p = 97.25 \text{ MHz}$; $f_q = 349.25 \text{ MHz}$.
- 5. $f_m = 548.5 \text{ MHz}$; $f_p = 109.25 \text{ MHz}$; $f_q = 439.25 \text{ MHz}$.
- 6. $f_m = 746.5 \text{ MHz}$; $f_p = 133.25 \text{ MHz}$; $f_q = 613.25 \text{ MHz}$.
- 7. $f_m = 854.5 \text{ MHz}$; $f_p = 133.25 \text{ MHz}$; $f_q = 721.25 \text{ MHz}$.
- 8. $f_m = 55.25 \text{ MHz}$; $f_p = 109.25 \text{ MHz}$; $f_q = 133.25 \text{ MHz}$ $f_r = 187.25 \text{ MHz}$.
- 9. $f_m = 445.25 \text{ MHz}$; $f_p = 193.25 \text{ MHz}$; $f_q = 349.25 \text{ MHz}$ $f_r = 97.25 \text{ MHz}$.
- 10. $f_m = 547.25 \text{ MHz}$; $f_p = 217.25 \text{ MHz}$; $f_q = 439.25 \text{ MHz}$ $f_r = 109.25 \text{ MHz}$.
- 11. $f_m = 745.25 \text{ MHz}$; $f_p = 133.25 \text{ MHz}$; $f_q = 265.25 \text{ MHz}$ $f_r = 613.25 \text{ MHz}$.
- 12. $f_m = 853.25 \text{ MHz}$; $f_p = 133.25 \text{ MHz}$; $f_q = 265.25 \text{ MHz}$ $f_r = 721.25 \text{ MHz}$.

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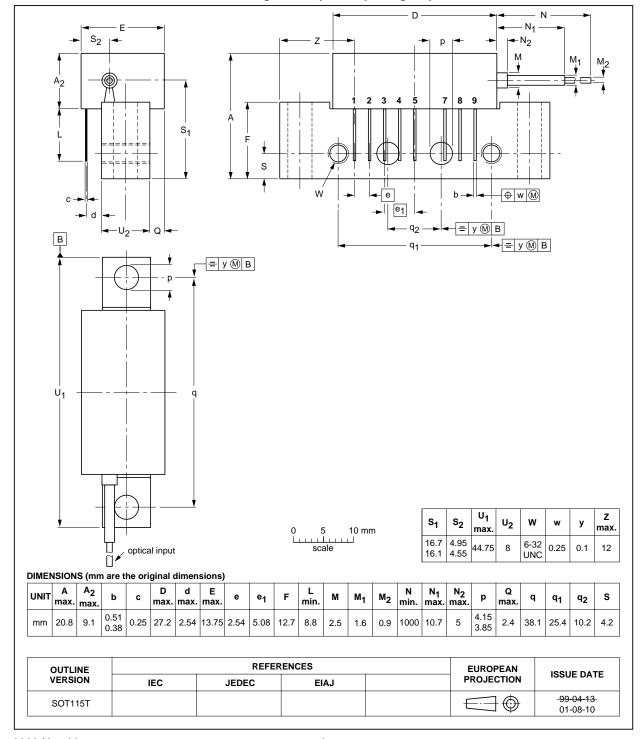
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BGO847

PACKAGE OUTLINE

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; optical input; 8 gold-plated in-line leads

SOT115T



870 MHz optical receiver

BGO847

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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